



**BSN20** 

#### N-CHANNEL ENHANCEMENT MODE FIELD MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
50V	$1.8\Omega @ V_{GS} = 10V$	500mA
	$2.0\Omega$ @ $V_{GS} = 4.5V$	450mA

#### **Description**

This new generation MOSFET has been designed to minimize the onstate resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Backlighting
- DC-DC Converters
- **Power Management Functions**

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

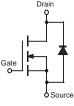
#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208@3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



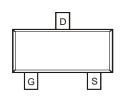
Top View





**Equivalent Circuit** 





Top View

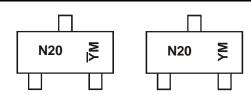
**Ordering Information (Note 5)** 

Part Number	Qualification	Case	Packaging
BSN20-7	Standard	SOT23	3000/Tape & Reel
BSN20Q-7	Automotive	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_grade\_definitions/
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



N20 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or  $\overline{Y}$  = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Chenadu A/T Site Shanghai A/T Site

Date Code Key									_			
Year	2009	9	2010		2011	20	12	2013		2014	2	2015
Code	W		X		Υ	2	7	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Charac	teristic		Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	50	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current @ T <sub>SP</sub> = +25°C (Note 6)	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I <sub>D</sub>	500 300	mA
Pulsed Drain Current @ T <sub>SP</sub> = +2	5°C (Notes 6 & 7)	)	I <sub>DM</sub>	1.2	Α

## **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Power Dissipation, @T <sub>A</sub> = +25°C (Note 6)	P <sub>D</sub>	600	mW
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	$R_{ hetaJA}$	200	°C/W
Power Dissipation, @T <sub>SP</sub> = +25°C (Note 6)	$P_{D}$	920	mW
Thermal Resistance, @T <sub>SP</sub> = +25°C (Note 6)	$R_{\theta JSP}$	136	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

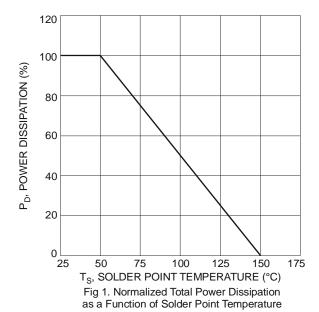
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

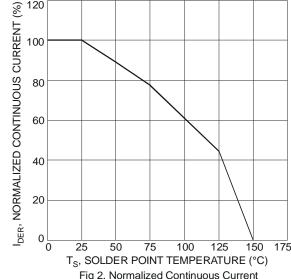
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			- 71	1			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	50	-	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	-	=	0.5	μA	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V	
Gate-Body Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			•		•		
Gate Threshold Voltage	$V_{GS(th)}$	0.4	1.0	1.5	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	1.3 1.6	1.8 2.0	Ω	$V_{GS} = 10V, I_D = 0.22A$ $V_{GS} = 4.5V, I_D = 0.1A$	
Forward Transfer Admittance	Y <sub>fs</sub>	40	320	-	mS	$V_{DS} = 10V, I_{D} = 0.1A$	
Diode Forward Voltage	$V_{SD}$	-	1.0	1.5	V	$V_{GS} = 0V, I_S = 180mA$	
Source (diode forward) Current	Is	-	_	194	mA	T <sub>SP</sub> = +25°C	
Peak Source (diode forward) Current	I <sub>SM</sub>	-	_	1.2	Α	T <sub>SP</sub> = +25°C (Notes 3 & 4)	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	-	21.8	40	pF		
Output Capacitance	Coss	-	5.6	15	pF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	3.3	10	pF		
Gate Resistance	$R_g$	-	49	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	$Q_g$	-	800	_	рC	101/1/	
Gate-Source Charge	$Q_{gs}$	Ī	100	_	рC	$V_{GS} = 10V, V_{DD} = 25V,$ $V_{DD} = 250 \text{mA}$	
Gate-Drain Charge	$Q_{gd}$	I	100	=	рC	- 1D - 230111A	
Turn-On Delay Time	t <sub>D(on)</sub>	ī	2.93	_	ns	1/ 201/1/ 101/	
Turn-On Rise Time	t <sub>r</sub>		2.99	=	ns	$V_{DD} = 30V, V_{GEN} = 10V,$ $R_{I} = 150\Omega, R_{GEN} = 50\Omega,$	
Turn-Off Delay Time	$t_{D(off)}$	-	9.45	=	ns	$R_L = 15002$ , $R_{GEN} = 5002$ , $I_D = 0.2A$	
Turn-Off Fall Time	t <sub>f</sub>	_	8.3	_	ns		

Notes:

- 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.
  7. Repetitive rating, pulse width limited by junction temperature.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to production testing.







120

Fig 2. Normalized Continuous Current vs. Solder Point Temperature

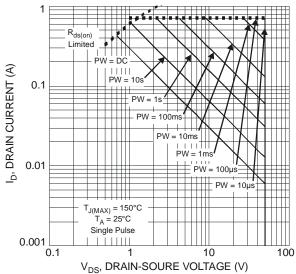


Fig. 3 SOA, Safe Operation Area

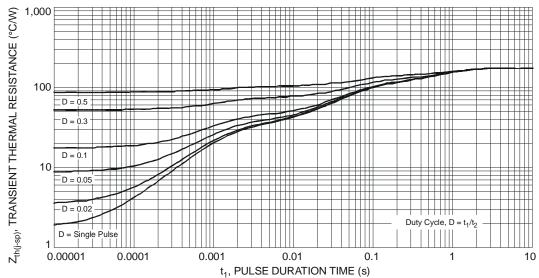
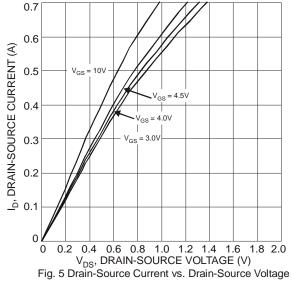
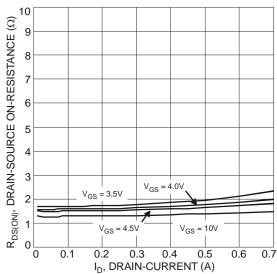
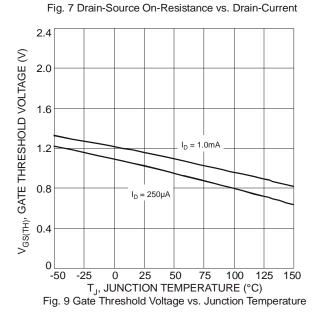


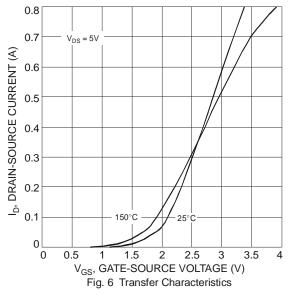
Fig. 4 Transient Thermal Response











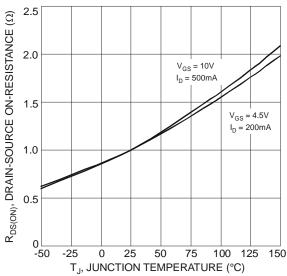
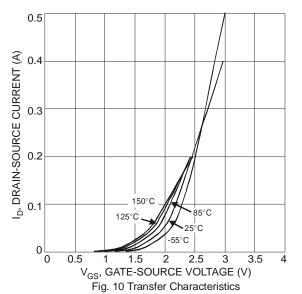
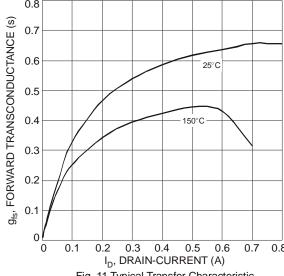
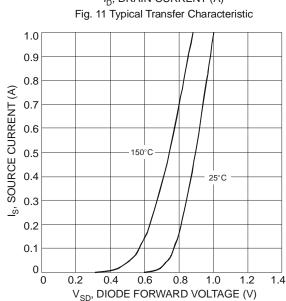


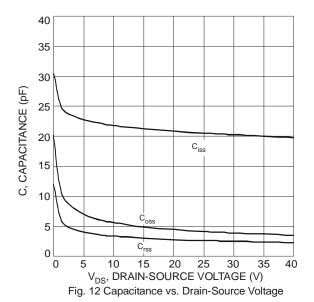
Fig. 8 Drain-Source On-Resistance vs. Junction Temperature







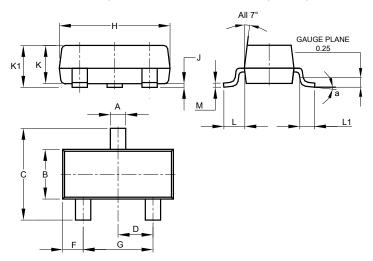




# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Fig. 13 Source Current vs. Diode Forward Voltage

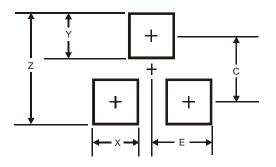


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890 1.00 0.975						
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
α	8°						
All	All Dimensions in mm						



## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35

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